FIG.1 A

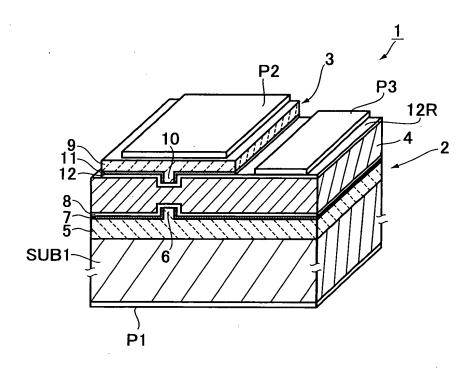
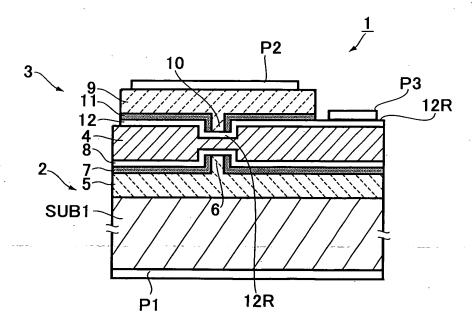


FIG.1 B



MANUFACTURING THE SAME Inventor's Name: MIYACHI et al Application No.: New Application Docket No.: 107156-00220 300 ≥ ∂ ETCHING ETCHING ≥ 9 FIG.2 F MM FIG.2 G FIG.2 E 200 9 9 9 9 <u>0</u> FIG.2 D 300 FIG.2 C FIG.2 A FIG.2 B

Title: SEMICONDUCTOR LASER DEVICE AND METHOD OF

FIG.3 A

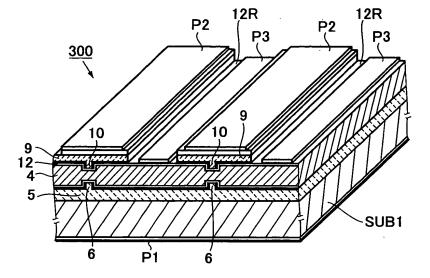
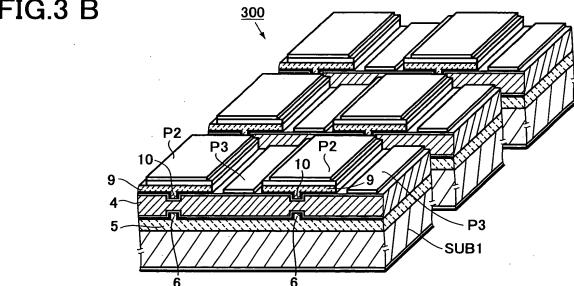


FIG.3 B



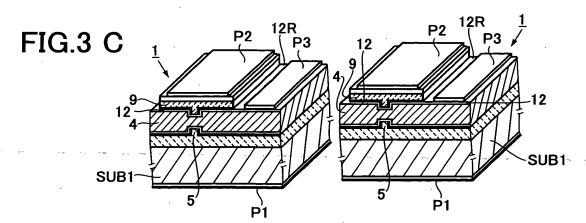


FIG.4 A

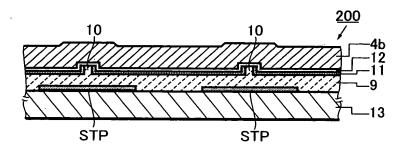


FIG.4 B

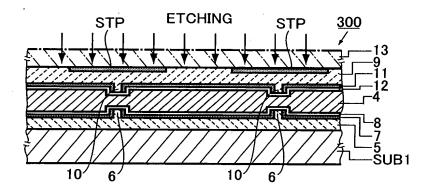


FIG.4 C

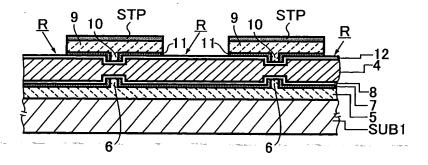
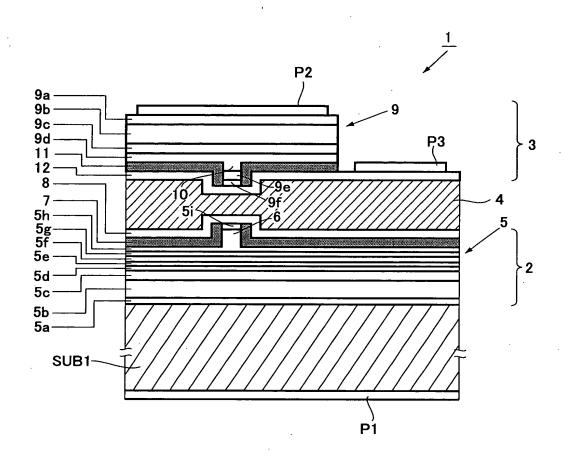
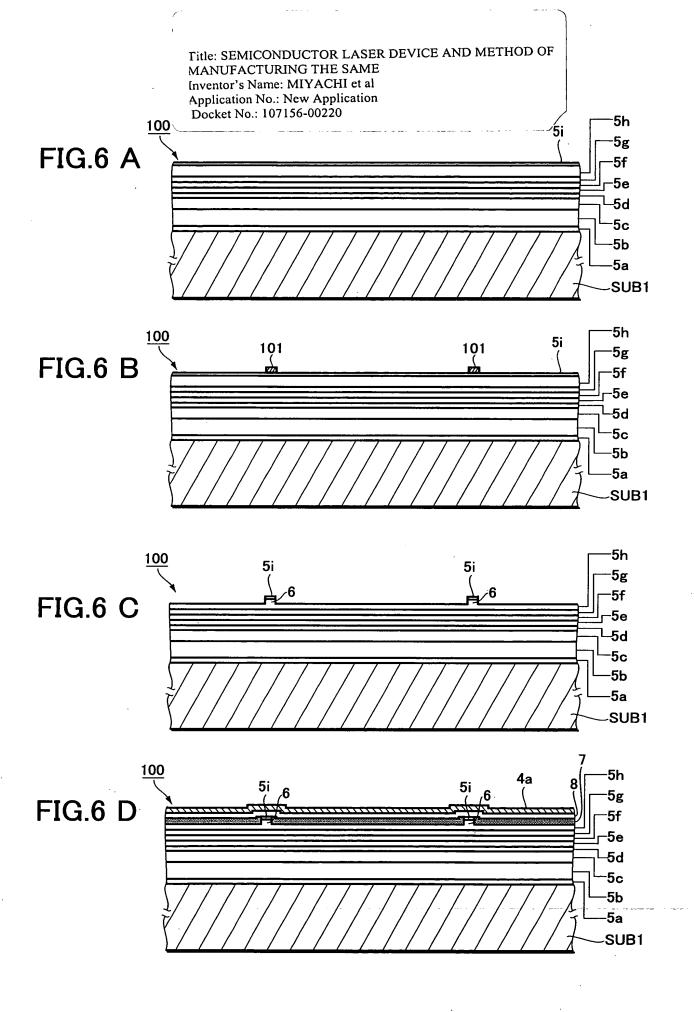
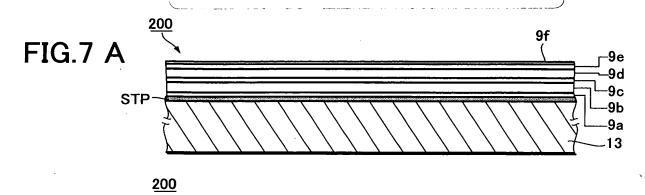
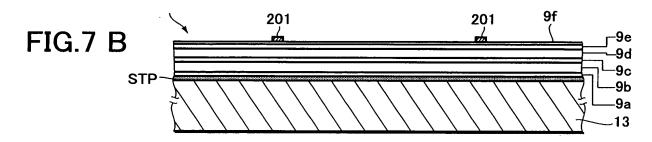


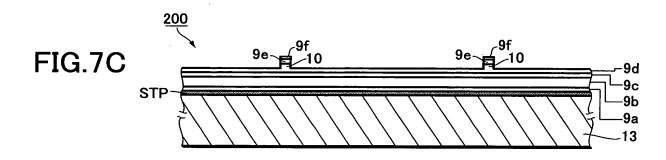
FIG.5











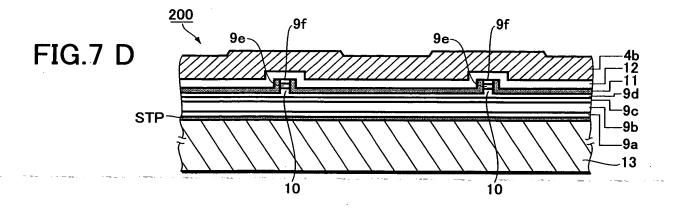
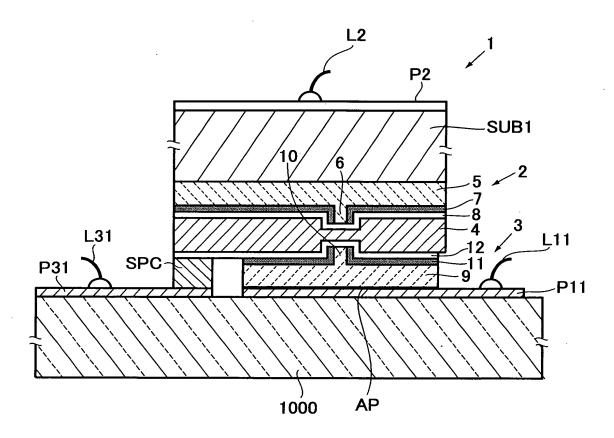


FIG.8



Title: SEMICONDUCTOR LASER DEVICE AND METHOD OF MANUFACTURING THE SAME

FIG.9 A

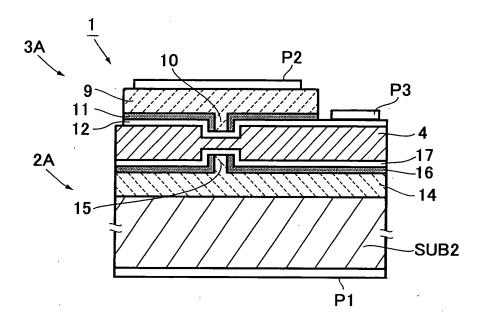
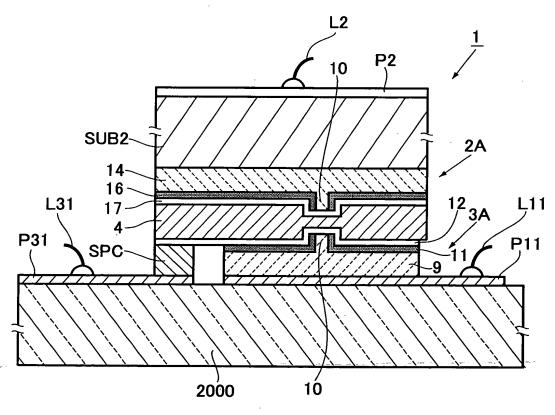


FIG.9 B



Title: SEMICONDUCTOR LASER DEVICE AND METHOD OF MANUFACTURING THE SAME Inventor's Name: MIYACHI et al

Application No.: New Application Docket No.: 107156-00220

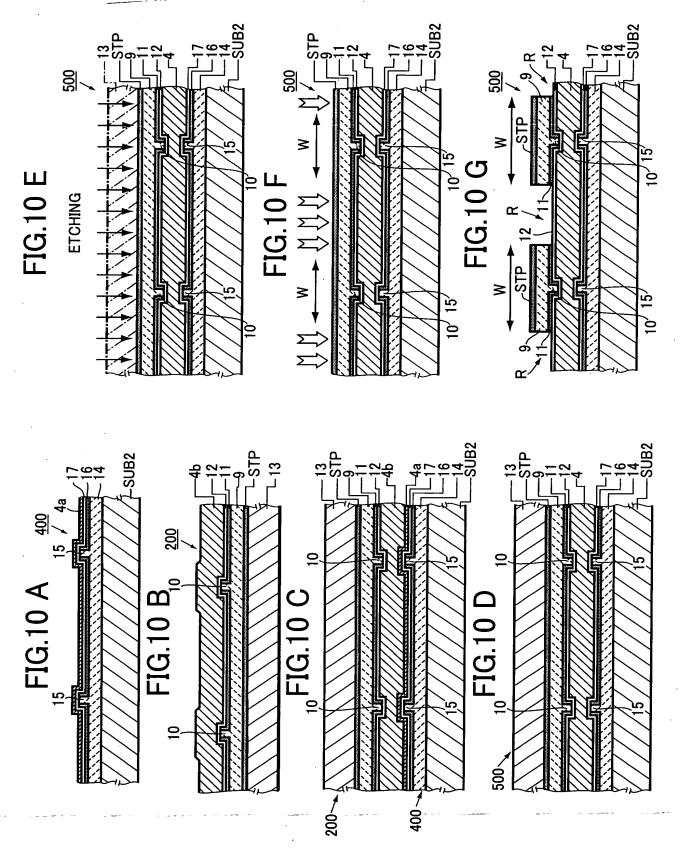


FIG.11 A

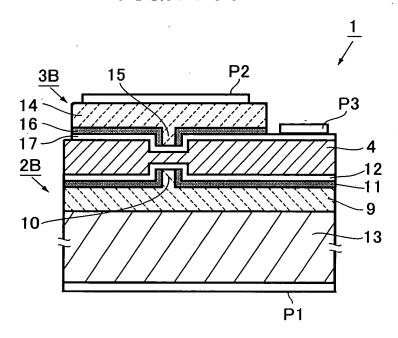
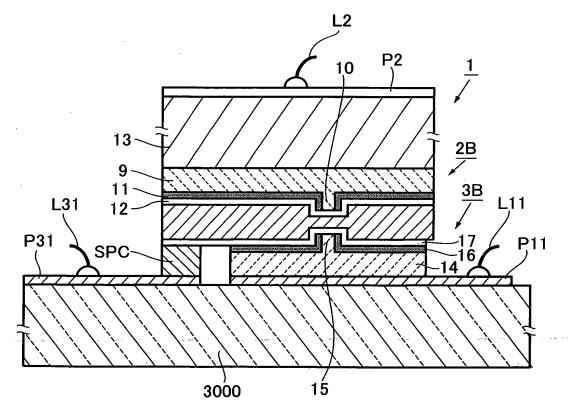
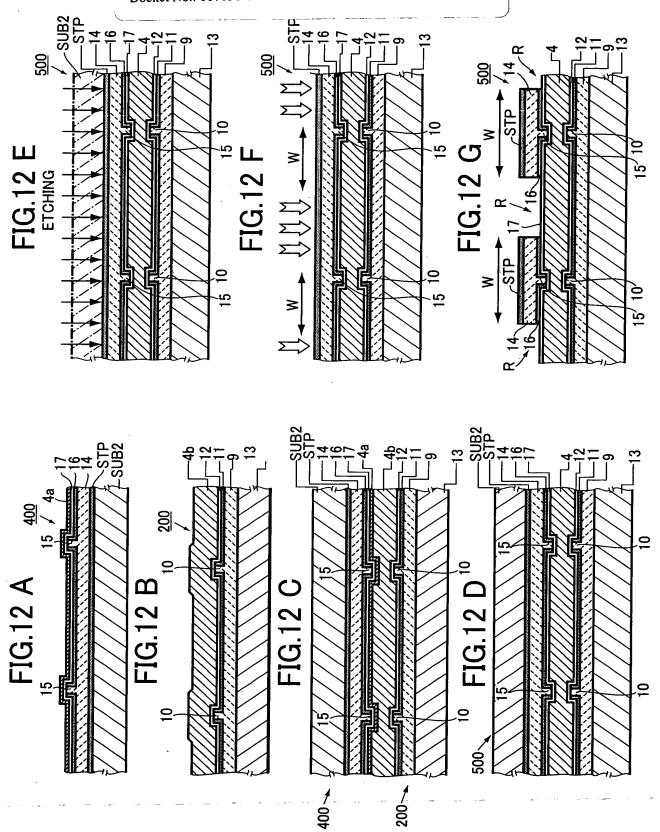


FIG.11 B





Title: SEMICONDUCTOR LASER DEVICE AND METHOD OF MANUFACTURING THE SAME

FIG.13 A

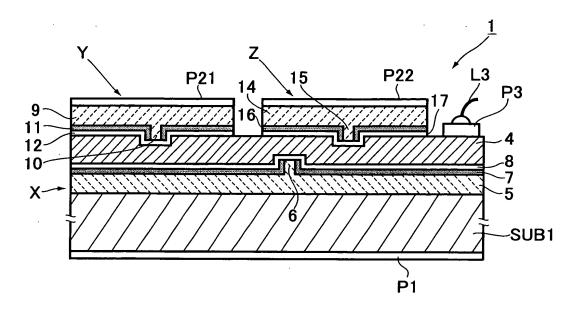


FIG.13 B

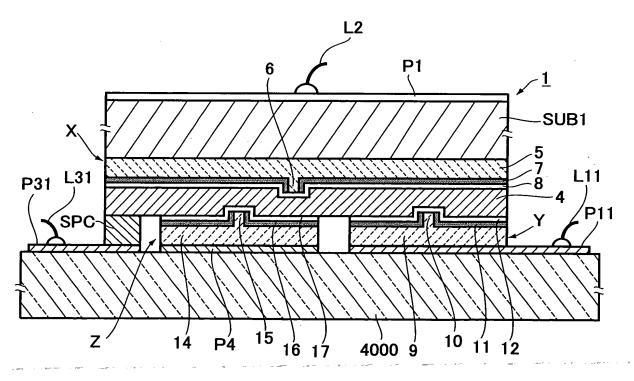


FIG.14 A

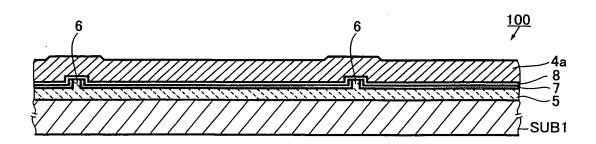


FIG.14 B

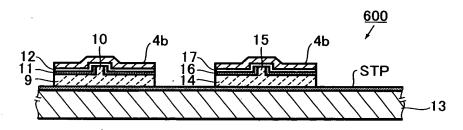


FIG.14 C

ETCHING

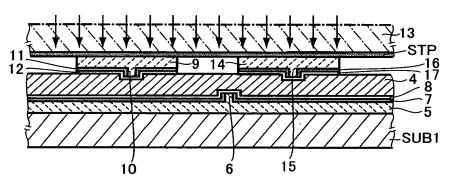


FIG.14 D

